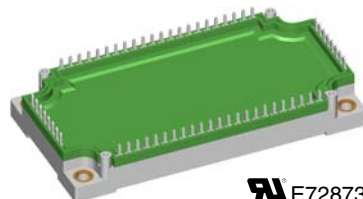
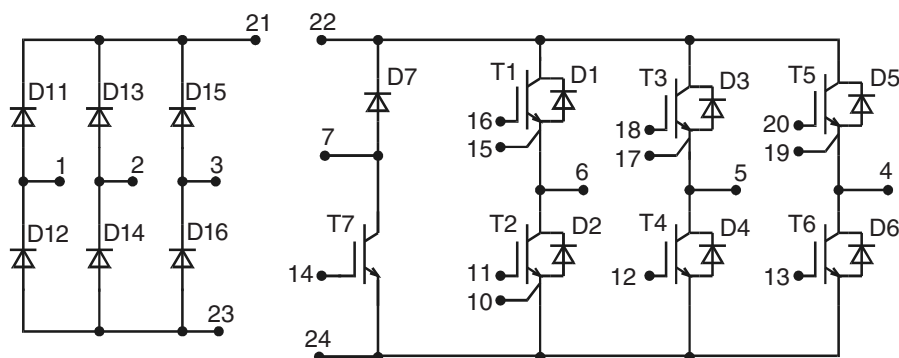


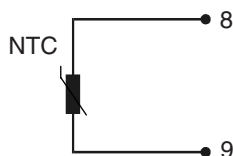
Converter - Brake - Inverter Module (CBI3)



E72873

See outline drawing for pin arrangement

Preliminary data



Three Phase Rectifier	Brake Chopper	Three Phase Inverter
$V_{RRM} = 1600\text{ V}$	$V_{CES} = 600\text{ V}$	$V_{CES} = 600\text{ V}$
$I_{FAVM} = 90\text{ A}$	$I_{C25} = 50\text{ A}$	$I_{C25} = 125\text{ A}$
$I_{FSM} = 850\text{ A}$	$V_{CE(sat)} = 1.9\text{ V}$	$V_{CE(sat)} = 1.9\text{ V}$

Input Rectifier D11 - D16

Symbol	Conditions	Maximum Ratings	
V_{RRM}		1600	V
I_{FAV}	$T_C = 80^\circ\text{C}$; sine 180°	65	A
I_{DAVM}	$T_C = 80^\circ\text{C}$; rectangular; $d = 1/3$; bridge	180	A
I_{FSM}	$T_{VJ} = 25^\circ\text{C}$; $t = 10\text{ ms}$; sine 50 Hz	850	A
P_{tot}	$T_C = 25^\circ\text{C}$	170	W

Symbol	Conditions	Characteristic Values ($T_{VJ} = 25^\circ\text{C}$, unless otherwise specified)		
		min.	typ.	max.
V_F	$I_F = 100\text{ A}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		1.3 1.3	1.5 V
I_R	$V_R = V_{RRM}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		1	0.05 mA mA
R_{thJC}	(per diode)			0.73 K/W

Application: AC motor drives with

- €Input from single or three phase grid
- €Three phase synchronous or asynchronous motor
- €electric braking operation

Features

- €High level of integration - only one power semiconductor module required for the whole drive
- €NPT IGBT technology with low saturation voltage, low switching losses, high RBSOA and short circuit ruggedness
- €Epitaxial free wheeling diodes with Hiperfast and soft reverse recovery
- €Industry standard package with insulated copper base plate and soldering pins for PCB mounting
- €Temperature sense included

Output Inverter T1 - T6

Symbol	Conditions	Maximum Ratings	
V_{CES}	$T_{VJ} = 25^{\circ}\text{C}$ to 150°C	600	V
V_{GES}	Continuous	± 20	V
I_{C25}	$T_C = 25^{\circ}\text{C}$	125	A
I_{C80}	$T_C = 80^{\circ}\text{C}$	85	A
RBSOA	$V_{GE} = \pm 15\text{ V}$; $R_G = 2.2\ \Omega$; $T_{VJ} = 125^{\circ}\text{C}$ Clamped inductive load; $L = 100\ \mu\text{H}$	$I_{CM} = 200$ $V_{CEK} \leq V_{CES}$	A
t_{SC} (SCSOA)	$V_{CE} = V_{CES}$; $V_{GE} = \pm 15\text{ V}$; $R_G = 2.2\ \Omega$; $T_{VJ} = 125^{\circ}\text{C}$ non-repetitive	10	μs
P_{tot}	$T_C = 25^{\circ}\text{C}$	410	W

Symbol	Conditions	Characteristic Values ($T_{VJ} = 25^{\circ}\text{C}$, unless otherwise specified)		
		min.	typ.	max.
$V_{CE(sat)}$	$I_C = 100\text{ A}$; $V_{GE} = 15\text{ V}$; $T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$	1.9 2.2		2.5 V
$V_{GE(th)}$	$I_C = 1.5\text{ mA}$; $V_{GE} = V_{CE}$	4.5		6.5 V
I_{CES}	$V_{CE} = V_{CES}$; $V_{GE} = 0\text{ V}$; $T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$	1.5		1.4 mA
I_{GES}	$V_{CE} = 0\text{ V}$; $V_{GE} = \pm 20\text{ V}$			400 nA
$t_{d(on)}$ t_r $t_{d(off)}$ t_f E_{on} E_{off}	Inductive load, $T_{VJ} = 125^{\circ}\text{C}$ $V_{CE} = 300\text{ V}$; $I_C = 100\text{ A}$ $V_{GE} = \pm 15\text{ V}$; $R_G = 2.2\ \Omega$		25 11 150 30 1.0 2.9	ns ns ns ns mJ mJ
C_{les}			4.3	nF
Q_{Gon}	$V_{CE} = 25\text{ V}$; $V_{GE} = 0\text{ V}$; $f = 1\text{ MHz}$ $V_{CE} = 300\text{ V}$; $V_{GE} = 15\text{ V}$; $I_C = 125\text{ A}$		340	nC
R_{thJC}	(per IGBT)			0.3 K/W

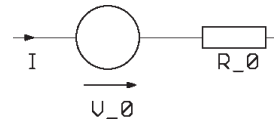
Output Inverter D1 - D6

Symbol	Conditions	Maximum Ratings	
I_{F25}	$T_C = 25^{\circ}\text{C}$	140	A
I_{F80}	$T_C = 80^{\circ}\text{C}$	85	A

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
V_F	$I_F = 100\text{ A}$; $V_{GE} = 0\text{ V}$; $T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$	1.9 1.4		2.2 V
I_{RM} t_{rr}	$I_F = 60\text{ A}$; $di_F/dt = -500\text{ A}/\mu\text{s}$; $T_{VJ} = 125^{\circ}\text{C}$ $V_R = 300\text{ V}$; $V_{GE} = 0\text{ V}$		28 100	A ns
R_{thJC}	(per diode)			0.61 K/W

Equivalent Circuits for Simulation

Conduction



IGBT (typ. at $V_{GE} = 15\text{ V}$; $T_J = 125^{\circ}\text{C}$)
T1-T6

$$V_0 = 1.05\text{ V}; R_0 = 11.5\text{ m}\Omega$$

T7

$$V_0 = 1.05\text{ V}; R_0 = 21.5\text{ m}\Omega$$

Diode (typ. at $T_J = 125^{\circ}\text{C}$)

D1-D6

$$V_0 = 1.15\text{ V}; R_0 = 2.5\text{ m}\Omega$$

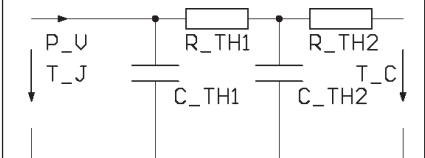
D7

$$V_0 = 1.15\text{ V}; R_0 = 12.5\text{ m}\Omega$$

D11-D16

$$V_0 = 0.85\text{ V}; R_0 = 4\text{ m}\Omega$$

Thermal Response



IGBT (typ.)

T1-T6

$$C_{th1} = 0.232\text{ J/K}; R_{th1} = 0.223\text{ K/W}$$

$$C_{th2} = 1.504\text{ J/K}; R_{th2} = 0.077\text{ K/W}$$

T7

$$C_{th1} = 0.123\text{ J/K}; R_{th1} = 0.419\text{ K/W}$$

$$C_{th2} = 0.944\text{ J/K}; R_{th2} = 0.131\text{ K/W}$$

Diode (typ.)

D1-D6

$$C_{th1} = 0.138\text{ J/K}; R_{th1} = 0.48\text{ K/W}$$

$$C_{th2} = 0.957\text{ J/K}; R_{th2} = 0.13\text{ K/W}$$

D7

$$C_{th1} = 0.038\text{ J/K}; R_{th1} = 1.74\text{ K/W}$$

$$C_{th2} = 0.435\text{ J/K}; R_{th2} = 0.36\text{ K/W}$$

D11-D16

$$C_{th1} = 0.112\text{ J/K}; R_{th1} = 0.568\text{ K/W}$$

$$C_{th2} = 0.745\text{ J/K}; R_{th2} = 0.162\text{ K/W}$$

Brake Chopper T7

Symbol	Conditions	Maximum Ratings	
V_{CES}	$T_{VJ} = 25^{\circ}\text{C}$ to 150°C	600	V
V_{GES}	Continuous	± 20	V
I_{C25}	$T_C = 25^{\circ}\text{C}$	75	A
I_{C80}	$T_C = 80^{\circ}\text{C}$	50	A
RBSOA	$V_{GE} = \pm 15\text{ V}$; $R_G = 22\ \Omega$; $T_{VJ} = 125^{\circ}\text{C}$ Clamped inductive load; $L = 100\ \mu\text{H}$	$I_{CM} = 100$ $V_{CEK} \leq V_{CES}$	A
t_{SC} (SCSOA)	$V_{CE} = V_{CES}$; $V_{GE} = \pm 15\text{ V}$; $R_G = 22\ \Omega$; $T_{VJ} = 125^{\circ}\text{C}$ non-repetitive	10	μs
P_{tot}	$T_C = 25^{\circ}\text{C}$	225	W

Symbol	Conditions	Characteristic Values ($T_{VJ} = 25^{\circ}\text{C}$, unless otherwise specified)		
		min.	typ.	max.
$V_{CE(sat)}$	$I_C = 50\text{ A}$; $V_{GE} = 15\text{ V}$; $T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$		1.9 2.1	V V
$V_{GE(th)}$	$I_C = 1\text{ mA}$; $V_{GE} = V_{CE}$	4.5		6.5 V
I_{CES}	$V_{CE} = V_{CES}$; $V_{GE} = 0\text{ V}$; $T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$		0.5	mA mA
I_{GES}	$V_{CE} = 0\text{ V}$; $V_{GE} = \pm 20\text{ V}$			200 nA
$t_{d(on)}$ t_r $t_{d(off)}$ t_f E_{on} E_{off}	Inductive load, $T_{VJ} = 125^{\circ}\text{C}$ $V_{CE} = 300\text{ V}$; $I_C = 50\text{ A}$ $V_{GE} = \pm 15\text{ V}$; $R_G = 22\ \Omega$		50 55 300 30 2.3 1.7	ns ns ns ns mJ mJ
C_{ies}			2.8	nF
Q_{Gon}			120	nC
R_{thJC}				0.55 K/W

Brake Chopper D7

Symbol	Conditions	Maximum Ratings		
V _{RRM}	T _{VJ} = 25°C to 150°C	600	V	
I _{F25}	T _C = 25°C	35	A	
I _{F80}	T _C = 80°C	24	A	
Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
V _F	I _F = 50 A; T _{VJ} = 25°C T _{VJ} = 125°C	2.2 1.8	2.5	V V
I _R	V _R = V _{RRM} ; T _{VJ} = 25°C T _{VJ} = 125°C	0.1	0.1	mA mA
I _{RM} t _{rr}	I _F = 15 A; di _F /dt = -400 A/μs; T _{VJ} = 125°C V _R = 300 V	13 90		A ns
R _{thJC}			2.1	K/W

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Temperature Sensor NTC

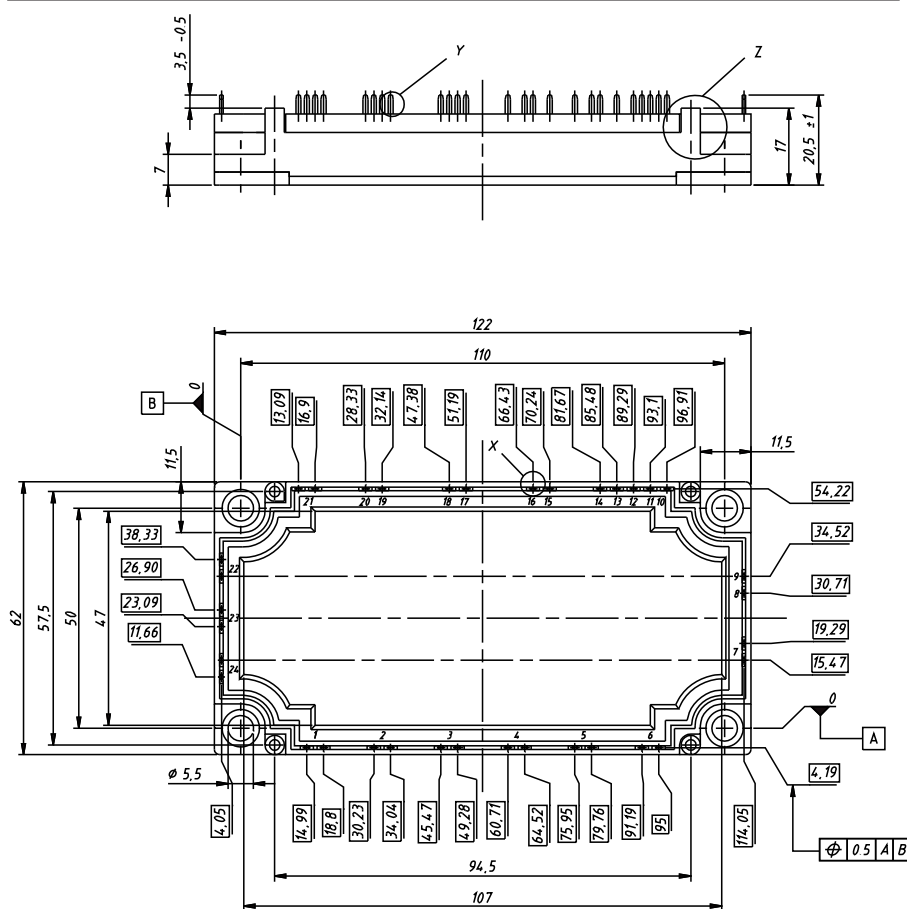
Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
R ₂₅	T = 25°C	4.75	5.0	5.25 kΩ
B _{25/50}			3375	K

Module

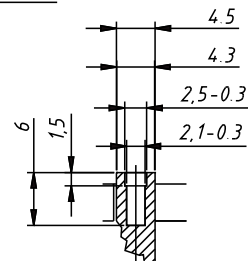
Symbol	Conditions	Maximum Ratings	
T_{VJ}	operating	-40...+125	°C
T_{JM}		+150	°C
T_{stg}		-40...+125	°C
V_{ISOL}	$I_{ISOL} \leq 1 \text{ mA}; 50/60 \text{ Hz}$	2500	V~
M_d	Mounting torque (M5)	3 - 6	Nm

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
$R_{\text{pin-chip}}$			5	mΩ
d_s	Creepage distance on surface	6		mm
d_A	Strike distance in air	6		mm
R_{thCH}	with heatsink compound		0.01	K/W
Weight			300	g

Dimensions in mm (1 mm = 0.0394")



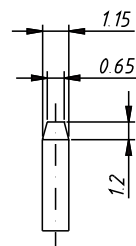
Detail Z



Detail X



Detail Y



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